

## TS7021N - 100W CW GaN Broadband RF Switch SPDT

#### 1.0 Features

• Low insertion loss: 0.65dB @ 1.9GHz

• High isolation: 37dB @ 1.9GHz

High linear power handling capability

No external DC blocking capacitors on RF lines

All RF ports OFF state

Versatile 2.6-5.5V power supply

Operating frequency: 500MHz to 2.7GHz





**Figure 1 Device Image** (32 Pin 5×5×1.25mm QFN Package)

# 2.0 Applications

- Private mobile and military radios
- Public safety handsets
- Cellular infrastructure
- Small cells
- LTE relays and microcells
- Satellite terminals



# RoHS/REACH/Halogen Free Compliance

# 3.0 Description

The TS7021N is a symmetrical reflective Single Pole Dual Throw (SPDT) switch designed for broadband, high power switching applications. With a simple broadband match, the TS7021N can cover 500M to 2.7GHz bandwidth and provide low insertion loss, high isolation and high linearity within a small package size. TS7021N is an excellent switch for all applications requiring low insertion loss, high isolation and high linearity within a small package size.

The TS7021N is packaged into a compact Quad Flat No lead (QFN) 5x5mm 32 leads plastic package.

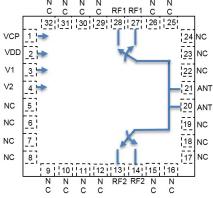


Figure 2 Function Block Diagram (Top View)

# 4.0 Ordering Information

# **Table 1 Ordering Information**

Base Part Number	Package Type	Form	Qty	Reel Diameter	Reel Width	Orderable Part Number
TS7021N	32 Pin 5×5×1.25mm QFN	Tape and Reel	3000	13" (330mm)	18mm	TS7021NMTRPBF
Evaluation Board						TS7021N-EVB



# 5.0 Pin Description

**Table 2 Pin Definition** 

Pin Number	Pin Name	Description
1	VCP	Internal charge pump voltage output. Connect a 1nF capacitor to
'	VCF	GND on this pin to improve switching time.
2	VDD	DC power supply
3	V1	Switch control input 1
4	V2	Switch control input 2
5,6,7,8,9,10,11,16,17,	NC	No internal connection, can be grounded
18,23,24,25,30,31,32	INC	No internal connection, can be grounded
12,15,19,22,26,29	NC	No internal connection. Do not connect to ground
13,14	RF2	RF port 2
20,21	ANT	Antenna port
27,28	RF1	RF port 1

**Note:** The backside ground (thermal) pad of the package must be grounded directly to the ground plane of PCB with multiple vias and adequate heat sinking must be used to ensure proper operation and thermal management.

# **6.0 Absolute Maximum Ratings**

Table 3 Absolute Maximum Ratings @T<sub>A</sub>=+25°C Unless Otherwise Specified

Parameter	Symbol	Value	Unit					
Electrical Ratings								
Power Supply Voltage	VDD	2.6 to 5.5	V					
Storage Temperature Range	T <sub>st</sub>	-55 to +125	°C					
Operating Temperature Range	Тор	-40 to +85	°C					
Maximum Junction Temperature	TJ	+140	°C					
RF Input Power CW, Tcase=+85°C, 800MHz	RFx	47	dBm					
RF Input Power CW, Tcase=+85°C, 2600MHz	RFx	46.5	dBm					
RF Input Power (VSWR 20:1), 2 minutes, 800MHz	RFx	45	dBm					
Thermal Rati	Thermal Ratings							
Thermal Resistance (junction-to-case) – Bottom side	Rejc	4.0	°C/W					
Soldering Temperature	Tsold	260	°C					
ESD Ratings								
Human Body Model (HBM)	Level 1B	500 to <1000	V					
Charged Device Model (CDM)	Level C3	≥1000	٧					
Moisture Rating								
Moisture Sensitivity Level	MSL	1	-					

#### Attention:

Maximum ratings are absolute ratings. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Exceeding one or a combination of the absolute maximum ratings may cause permanent and irreversible damage to the device and/or to surrounding circuit.



# 7.0 Electrical Specifications

**Table 4 Electrical Specifications** @T<sub>A</sub>=+25°C Unless Otherwise Specified; VDD=+2.7V; 50Ω Source/Load.

Parameter	Condition	Minimum	Typical	Maximum	Unit
Operating frequency		500		2700	MHz
	800MHz		0.50	0.60	
Insertion loss, RFx	1.95GHz		0.65	0.75	dB
	2.6GHz		0.70	0.85	
	800MHz	41	45		
Isolation ANT-RFx	1.95GHz 33 37			dB	
	2.6GHz	30	34		
	800MHz		19		
Return loss ANT,	1.95GHz		20		dB
RFx	2.6GHz		25		
Harmonic distortion					
H2	800MHz, Pin=45dBm		-74		dBc
H3	800MHz, Pin=45dBm		-70		dBc
IIP3	800MHz		71		dBm
P0.1dB <sup>[1]</sup>	0.1dB compression point, 500MHz ~ 1.5GHz		50		dBm
P0.1dB <sup>[1]</sup>	0.1dB compression point, 1.5GHz ~ 2.7GHz		49.0		dBm
Switching time	50% ctrl to 10/90% of the RF value is settled. CP=1nF to ground on VCP pin.		1.5		μS
Control voltage	Power Supply VDD	2.6	3.3	5.5	V
	All control pins high, V <sub>ih</sub>	1.0	3.3	5.25	V
	All control pins low, V <sub>il</sub>	-0.3		0.5	V
Control current	All control pins low, Iii		0		μА
	All control pins high, I <sub>ih</sub>			7.5	μΑ
Current consumption, IDD	Active mode (VDD on)		160	200	μΑ

#### Note:

<sup>[1]</sup> P0.1dB is a figure of merit.

<sup>[2]</sup> No external DC blocking capacitors required on RF pins unless DC voltage is applied on a RF pin.



#### 8.0 Switch Truth Table

**Table 5 Switch Truth Table** 

V1	V2	Active RF Path
0	1	All OFF
0	0	ANT-RF1 ON
1	0	ANT-RF2 ON

#### Attention:

- [1] VDD should be applied first before V1 and V2, otherwise may cause damage to the device.
- [2] There are internal pull-downs to ground on both V1 and V2 control pins, the state at start-up without any control voltage applied will be ANT-RF1 ON.
- [3] If all OFF state is not used, the switch can be operated with single control pin V1.

#### 9.0 Evaluation Board

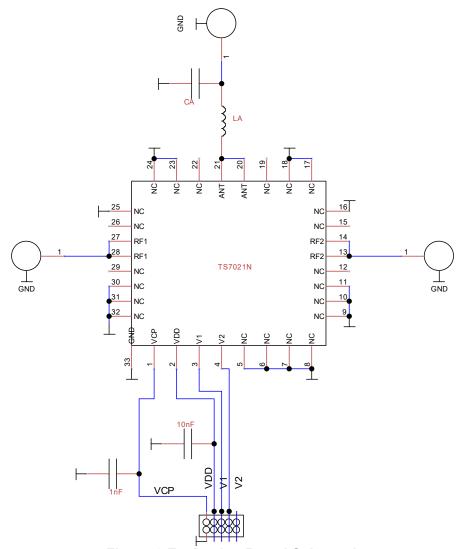


Figure 3 Evaluation Board Schematic



#### Attention:

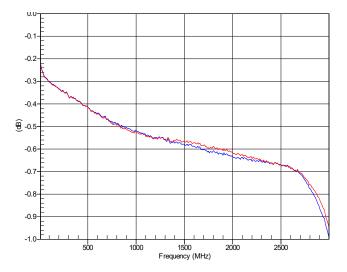
- [1] 33 refers to the center pad of the device. Multiple Plugged through hole vias should be added on this Ground Pad and adequate heat sinking should be used.
- [2] The purpose of connection between VCP and connector N1 is to monitor VCP, do not apply external voltage to VCP.
- [3] Place matching components close to pin of the part.

**Table 6 Recommended Evaluation Board Component Values** 

Reference Designator	Value	Part #	Manufacturer
LA	1.6nH	0603HC-1N6XJLU	Coilcraft
CA	0.9pF	0603N0R9BW251	Passive Plus Inc



# **10.0 Typical Characteristics**



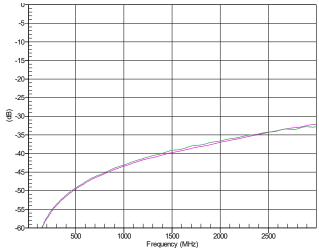
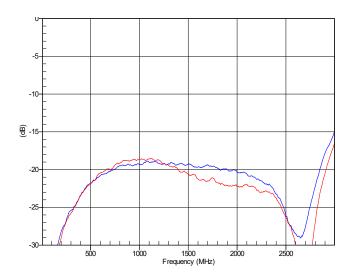


Figure 4 RF1, RF2 Insertion Loss

Figure 5 RF1, RF2 Isolation



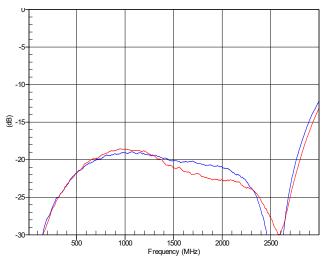


Figure 6 RF1, RF2 Return Loss

Figure 7 ANT Return Loss



## 11.0 Device Package Information

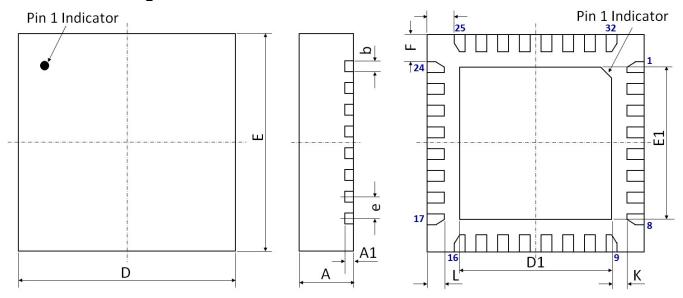


Figure 12 Device Package Drawing

(All dimensions are in mm)

**Table 7 Device Package Dimensions** 

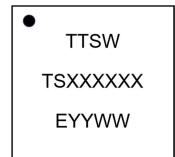
Dimension (mm)	Value (mm)	Tolerance (mm)	Dimension (mm)	Value (mm)	Tolerance (mm)
Α	1.25	±0.05	E	5.00 BSC	±0.05
A1	0.203	±0.02	E1	3.10	±0.06
b	0.25	+0.05/-0.07	F	0.625	±0.05
D	5.00 BSC	±0.05	G	0.625	±0.05
D1	3.10	±0.06	L	0.40	±0.05
е	0.50 BSC	±0.05	K	0.50	±0.05

**Note:** Lead finish: Pure Sn without underlayer; Thickness: 7.5μm ~ 20μm (Typical 10μm ~ 12μm)

#### Attention:

Please refer to application notes *TN-001* and *TN-003* at http://www.tagoretech.com for PCB and soldering related guidelines.

#### **Top-marking specification:**



= Pin 1 indicator

TTSW = Tagore Technology SWitch

TSXXXXXX = Part number (8 digits max)

E = A fixed letter before the date code

YY = Last two digits of assembly year

WW = Assembly work week



# 12.0 PCB Land Design

#### **Guidelines:**

- [1] 4 layer PCB is recommended.
- [2] Via diameter is recommended to be 0.2mm to prevent solder wicking inside the vias.
- [3] Thermal vias shall only be placed on the center pad.
- [4] The maximum via number for the center pad is  $5(X)\times 5(Y)=25$ .

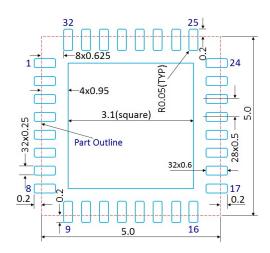


Figure 8 PCB Land Pattern

(Dimensions are in mm)



Figure 9 Solder Mask Pattern

(Dimensions are in mm)

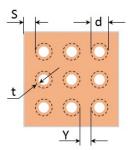


Figure 10 Thermal Via Pattern

(Recommended Values: S≥0.15mm; Y≥0.20mm; d=0.2mm; Plating Thickness t=25µm or 50µm)



## 13.0 PCB Stencil Design

#### **Guidelines:**

- [1] Laser-cut, stainless steel stencil is recommended with electro-polished trapezoidal walls to improve the paste release.
- [2] Stencil thickness is recommended to be 125µm.

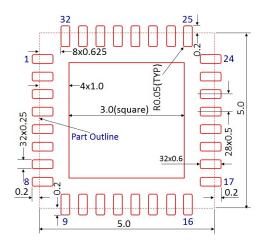


Figure 11 Stencil Openings (Dimensions are in mm)

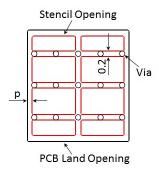
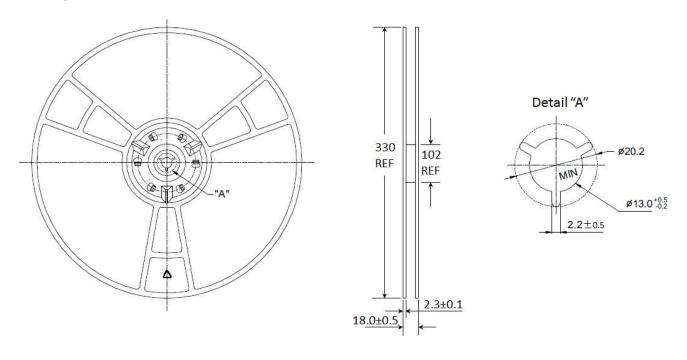


Figure 12 Stencil Openings Shall not Cover Via Areas If Possible (Dimensions are in mm)



# 14.0 Tape and Reel Information



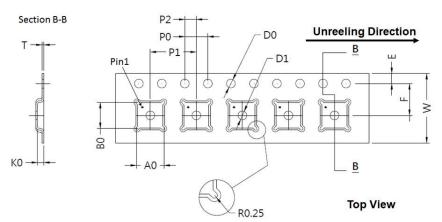


Figure 13 Tape and Reel Drawing

**Table 8 Tape and Reel Dimensions** 

Dimension (mm)	Value (mm)	Tolerance (mm)	Dimension (mm)	Value (mm)	Tolerance (mm)
A0	5.35	±0.10	K0	1.10	±0.10
В0	5.35	±0.10	P0	4.00	±0.10
D0	1.50	+0.10/-0.00	P1	8.00	±0.10
D1	1.50	+0.10/-0.00	P2	2.00	±0.05
E	1.75	±0.10	Т	0.30	±0.05
F	5.50	±0.05	W	12.00	±0.30



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